

KEY FEATURES

- Output power: 200 kW
- DC, 1-ph or 3-ph AC output
- Four-quadrant operation
- Regenerative
- Scalable up to 1,2 MW & 3000 V DC
- AC output voltage L-L: 485 V RMS
- AC output current: 240 A RMS
- DC output voltage: 820 V
- DC output current: 840 A

- Large-signal BW: 5 kHz
- Small-signal BW: 15 kHz
- Programmable V and I limits
- Voltage accuracy: 0,1%
- Current accuracy: 0,56%
- Peak efficiency: 95%
- Frequency accuracy: 1 mHz
- Meets IEEE 1547.1
- CE Certified





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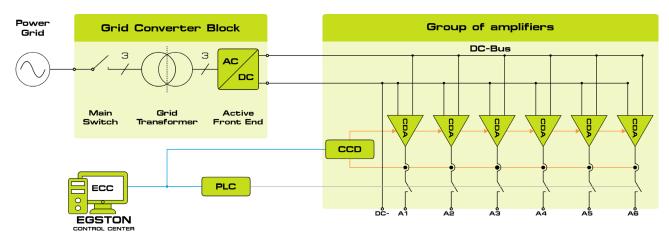
SYSTEM INTRODUCTION

CSU200-1GAMP6-HV (COMPISO System Unit 200 – one Group of six Amplifiers – High Voltage) is a galvanically isolated bidirectional 200 kW emulation and test system with six independent bidirectional switched-mode power amplifiers capable of operating in several predefined AC and DC operation modes as well as a wide range of user-defined Hardware-in-the-loop (HIL)-based modes. The system can operate in current-control, voltage-control or mixed mode and is capable of acting as a source or sink with seamless transition between sourcing power and regenerating power back to the supply grid. Featuring large-signal bandwidth of 5 kHz and small-signal bandwidth of 15 kHz, the system can generate harmonics up to the 100th order and interharmonics up to 15 kHz for smooth frequency sweeps. The CSU200-1GAMP6-HV is controlled by an EGSTON Real-Time (RT) Processor or external HIL systems via fast optic fiber (SFP-Small Form Factor Pluggable) or analog interface.

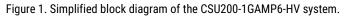
The optional 4QAC Source software application enables generation of arbitrary periodic waveforms whose amplitude, frequency, phase (time shift) and DC offset can be changed every 1 ms. The active and reactive power can be changed separately in each phase every 1 ms, enabling more complex test scenarios such as Low Voltage Ride Through, High Voltage Ride Through, and frequency drift.

The optional 4QDC Source software application can execute various DC tests, ranging from constant-current, constant-voltage or constant-power operation to more advanced scenarios such as emulation of PV arrays and batteries modelled on I-V curves.

The optional PowerSCOPE can be used to monitor system setpoints and generated output voltages and currents. It supports visualization and storage of up to 64 input channels with a sample rate of 250 kS/s per channel.



SYSTEM DESCRIPTION & OPERATION MODES



The CSU200-1GAMP6-HV connects to a three-phase + N power grid (three-phase four wire system) via a galvanic isolation transformer. A protective earth (PE) connection providing adequate grounding must also be available. The system can be adapted to any three-phase power grid voltage from 400–690 V at 50 or 60 Hz. The transformer feeds a bidirectional Active Front End (AFE) that converts the grid's AC voltage to a controlled DC-link voltage of 850 V. The maximum active power that can be sourced from or regenerated to the grid is 200 kVA. The CSU200-1GAMP6-HV consists of six COMPISO Digital Amplifiers (CDAs). This amplifier group is controlled by one COMPISO Control Device (CCD) and one Programable Logic Controller (PLC). The output voltage and current of each amplifier are measured at its output terminal.

The CSU200-1GAMP6-HV system consists of four cabinets and a desktop PC with EGSTON Control Center (ECC) software used to monitor, configure and control the system operating in any of the standard operation modes illustrated in Figure 2



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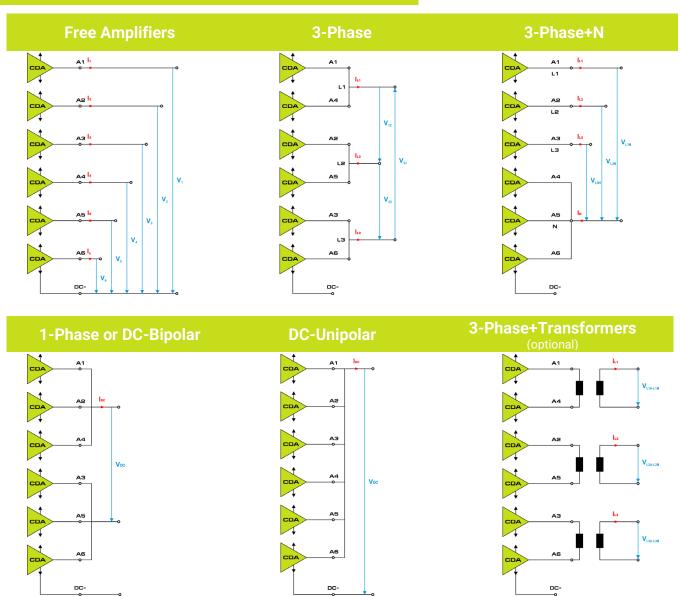


Figure 2. CSU200-1GAMP6-HV operation modes.

The available voltage, current, and power range in each operation mode are listed in Table 1. In each operation mode, the system can either operate as a power source or regenerate power back to the grid. The values listed in Table 1 are valid for both directions. In order to increase the output voltage in three-phase operation modes, with or without the neutral terminal, a third harmonic injection can be used. Output power is limited to 200kW in DC bipolar and DC unipolar operation modes by voltage or current derating, as illustrated in Figure 3.



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Table 1. Available voltage, current and power range in each operation mode.

Operation mode: Free amplifie	rs (all values are p	per CDA)	
AC mode ¹			
DC offset voltage	V _{DC}	420 V _{DC}	
Minimum AC voltage	V _{min}	0 V _{RMS}	
Maximum AC voltage	V _{max}	280 V _{RMS}	
Minimum AC current	I _{min}	0 A _{RMS}	
Maximum AC current	I _{max}	120 A _{RMS}	
Maximum active power	P _{max}	34,0 kW	
Maximum apparent power	S _{max}	34,0 kVA	
DC mode (unipolar)			
Minimum DC voltage	V _{min}	20 V _{DC}	
Maximum DC voltage	V _{max}	820 V _{DC}	
Minimum DC current	I _{min}	-140 A _{DC}	
Maximum DC current	I _{max}	140 A _{DC}	
Maximum power	P _{max}	100 kW	
Operation mode: Three-phase	+ N		
Minimum LL voltage	V_{LLmin}	0 V _{RMS}	
Maximum LL voltage	V _{LL max}	485 V _{RMS}	
Maximum LN voltage	$V_{\text{LN max}}$	280 V _{RMS}	
Minimum current	I _{L min}	0 A _{RMS}	
Maximum current	I _{L max}	120 A _{RMS}	
Maximum active power	P _{max}	100 kW	
Maximum apparent power	S _{max}	100 kVA	
Operation mode: Three-phase			
Minimum LL voltage	V_{LLmin}	0 V _{RMS}	
Maximum LL voltage	V _{LL max}	485 V _{RMS}	
Minimum current	I _{L min}	0 A _{RMS}	
Maximum current	I _{L max}	240 A _{RMS}	
Maximum active power	P _{max}	200 kW	
Maximum apparent power	S _{max}	200 kVA	



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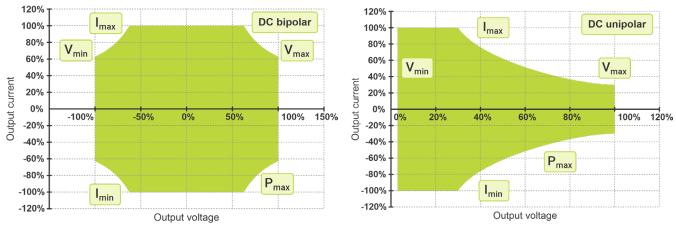
		Table 1. (continued)
Operation mode: Three-phase	+ N (with 3rd ha	monic injected)
Minimum LL voltage	V _{LL min}	0 V _{RMS}
Maximum LL voltage	V _{LL max}	555 V _{RMS}
Maximum LN voltage	V _{LN max}	320 V _{RMS}
Minimum current	I _{L min}	0 A _{RMS}
Maximum current	I _{L max}	120 A _{RMS}
Maximum active power	P _{max}	115 kW
Maximum apparent power	S _{max}	115kVA
Operation mode: Three-phase	(with 3rd harmo	nic injected)
Minimum LL voltage	V _{LL min}	0 V _{RMS}
Maximum LL voltage	$V_{\text{LL}\text{max}}$	555 V _{RMS}
Minimum current	I _{L min}	0 Arms
Maximum current	I _{L max}	240 A _{RMS}
Maximum active power	P _{max}	200 kW
Maximum apparent power	S _{max}	230 kVA
Operation mode: Three-phase	+ transformers (n = V _s /V _p ; x = 1, 2, 3)
Minimum voltage	V_{Lx}	0 V
Maximum voltage	$V_{\text{Lx}\text{max}}$	n×565 V
Minimum current	I _{Lx min}	0 A
Maximum current	I _{Lx max}	(1/n)x120 A
Maximum power	S _{max}	200 kVA
Operation mode: Single-phase	2	
Minimum voltage	V _{min}	$0 V_{\text{RMS}}$
Maximum voltage	V _{max}	565 V _{RMS}
Maximum current	I _{max}	360 A _{RMS}
Maximum active power	P _{max}	200 kW
Maximum apparent power	S _{max}	200 kVA
Operation mode: DC bipolar		
Minimum voltage	V _{min}	-800 V
Maximum voltage	V _{max}	800 V
Minimum current	I _{min}	-420 A
Maximum current	I _{max}	420 A
Maximum power	P _{max}	200 kW
Operation mode: DC unipolar		
Minimum voltage	V _{min}	20 V
Maximum voltage	V _{max}	820 V
Minimum current	I _{min}	-840 A
Maximum current	I _{max}	840 A
Maximum power	P _{max}	200 kW
	-	

¹ The CDA output voltage has a DC offset of 420 V (with respect to the DC- terminal).

² Due to single-phase load on the AFE, power derating applies if the output voltage frequency is less than 100 Hz, as shown in Figure 8



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For all AC operation modes, the maximum available output voltage is reduced at higher output frequencies as illustrated in Figure 4 (for resistive loads) and Figure 5 (for inductive loads). This reduction is due to an increased voltage drop across the internal output filter at higher output frequencies. Output voltage derating additionally applies at frequencies above 5 kHz to avoid overheating the output filter capacitors, as illustrated in Figure 6, and output current derating at higher frequencies is necessary to avoid overheating the internal output inductor, as illustrated in Figure 7.

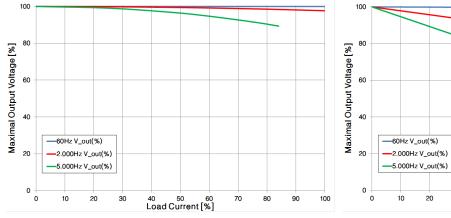


Figure 4. Maximum AC output voltage VS resistive load current

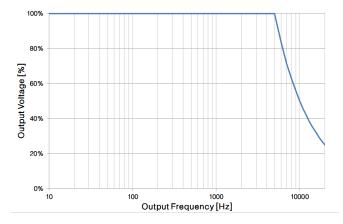
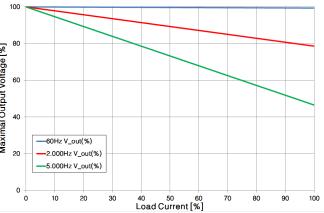


Figure 6. Maximum output voltage versus output frequency.



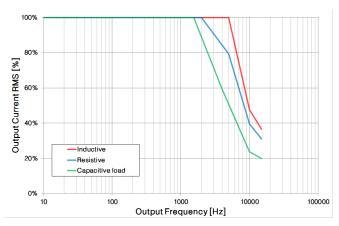


Figure 5. Maximum AC output voltage VS inductive load current.

Figure 7. Maximum output current versus frequency for different load types.



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When the system operates in single-phase operation mode, the output power needs to be derated depending on the output frequency according to Figure 8. Derating is introduced to limit the variation of the DC-link voltage under safe operating voltage limit (875 V). The Red line in Figure 8 represents the output power of the standard system, and the blue line represents the power of the system with the additional 30 mF (\pm 5%) capacitors of the DC link. At full capacity P_{MAX} corresponds to 200 kW. For each AC operation mode, the values in Figures 4-8 represent the percentages of the maximum voltage and current values from Table 1 for each particular mode.

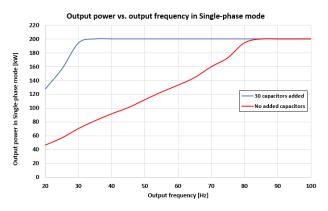


Figure 8. Power derating in single-phase operation mode.



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GENERAL SYSTEM PROPERTIES

The electrical properties presented in Table 2. General system properties are valid for an ambient temperature of 25°C.

Table 2. General system properties

stem properties				
Number of independent amplifiers		6		
Rated system power	Pout	200 kW		
System overload for 60 s	I _{OUT_60s}	$1,2 \times I_{OUT}$ (only for DC operation modes)		
System overload for 2 s	I _{OUT_2s}	$1,35 \times I_{OUT}$ (only for DC operation modes)		
Peak system efficiency	η	95% (at rated output power)		
Output harmonics range		Up to the 100th harmonic at 50 Hz fundamental		
Interharmonics and subharmonics		0,1 Hz to 5 kHz (full voltage)		
		5–15 kHz (reduced voltage)		
Adjustable limits		Current, voltage		
Adjustable trips		Current, voltage, power		
System protections		Overvoltage, overcurrent, short circuit, overtemperature, humidity		
Rated insulation voltage		1600 V_{DC} (output-to-output and output-to-ground)		
Connection to main supply		Permanent		
Overvoltage category		II		
Protection class		1		
Degree of pollution		2		
Relative humidity (Non-condensing)		Average: 75% Maximum: 85% for up to 30 days, distributed evenly over the year		
Operating ambient temperature		5-30°C		
Maximum altitude		2000 m		
Ingress protection		IP44 (per IEC 60529)		
Noise level (sound pressure level)		< 82 dB (at operator's normal position and bystanders' positions)		
rtification				
CE Certified				
The product conforms with the foll	owing harmoni	ized standards:		
Safety requirements		EN 61010-1:2020		
		EN 62477-1:2012		
		IEC 61000-6-2:2016		
Radio-frequency disturbance		EN 55011:2016 + A1:2017		
Electromagnetic interference		EN IEC 61000-6-2:2019		
The product is compliant with the t	following Europ	pean regulations:		
Low Voltage Directive		2014/35/EU		
EMC Directive		2014/30/EU		
RoHS Directive		2011/65/EU		



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Table 2. (continued)

	Table 2. (continued)		
	Three phase four wire		
S _{IN}	230 kVA		
V _{AC}	400 V _{RMS} ±10% (or 480 V _{RMS} ±10%)		
f	47,5–63 Hz		
I _{IN}	332 A_{RMS} (for 400 V_{RMS} input), 277 A_{RMS} (for 480 V_{RMS} input)		
I _{INRUSH}	1760 А _{РЕАК}		
PF	≈1 (also with partial load and at energy regeneration)		
THDi	< 5%		
$V_{\text{DC-link}}$	850 V		
P _{DC}	117,6 kW (continuous)		
P _{AC}	34,00 kVA (continuous)		
f _{OUT_LS}	0,1 Hz to 5 kHz		
f _{out_ss}	0,1 Hz to 15 kHz		
	±1 mHz		
	±0,01°		
THDu	< 0,04% (at 50/60 Hz, no load condition)		
	< 0,09% (at 400 Hz, no load condition)		
f _{SW}	125 kHz		
t _d	28 μs (setpoint-to-output)		
SR	12 V/ μ s (maximum slew rate of output voltage with a resistive load)		
	±1 V		
	±1,4 A (current offset compensation available)		
ΔV_{OUT}	3 Vpp maximum		
U _e	1800 V_{DC} or V_{AC} RMS		
Ui	1800 V _{DC} or V _{AC} RMS		
l _e	250 A		
s (per pole)	5000 A		
).8 (per pole)	5000 A		
ns (per pole)	500		
8.8 (per pole)	800 A		
ent			
	±1000 V (DC or AC peak)		
	±500 V (DC or AC peak)		
	±1 V (0.1% of measurement range)		
	±250 A (DC or AC peak)		
	±1,4 A (0,56% of measurement range)		
	16 bit		
	1 MS/s (per channel)		
	0,1 Hz–100 kHz (-3 dB)		
	VAC f IIN IINRUSH PF THDi VDC-link PDC PAC fout_LS fout_SS THDU fsw td SR Ue Ui Ie S (per pole) A (per pole) SR (per pole) S.8 (per pole) S.8 (per pole)		



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³ Only the AC component of the output voltage is considered, as the CDA output voltage has a DC offset of 420 V. The values characterizing AC operation are valid for all AC modes.

COMMUNICATION ARCHITECTURE & INTERFACES

The basic properties of the communication protocols and interfaces supported by the CSU200-1GAMP6-HV are presented in Table 3, and the communication architecture is illustrated in Figure 9. Supported HIL platforms are listed in Table 3.

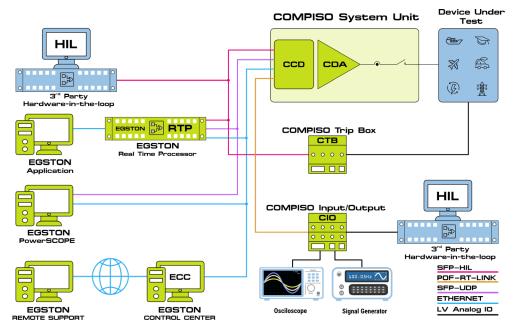


Figure 9. COMPISO communication architecture.

Table 3. Communication protocols and interfaces supported by the CSU200-1GAMP6-HV

Supported commercial HIL platforms

log interface	Any HIL system with low-voltage analog input/output signals
	dSPACE
	Typhoon HIL
SFP interface	Speedgoat
	RTDS
	National Instruments
	OPAL-RT

Programming interfaces

Modbus, Matlab, Python, Java, C/C++

SFP-HIL ultra-high-speed interface

Digital RT communication between each GAMP within the CSU and an external HIL RT processor (or an EGSTON Power RT Processor) over optic-fibre cable. Receives voltage or current setpoints and transmits measured voltages and currents.

Data rate	5 Gbps
Latency	≤ 1 µs
Setpoint time step	4 µs
Setpoint update frequency	250 kHz



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Table 3. (continued)

P-UDP							
Digital RT data transfer from the GA		e EGSTON PowerSCOPE, transn	nitting measured voltages,				
currents and setpoints set via the SFF							
Data rate		1000BASE-T)					
hernet interface (non-RT commun		CC and EGSTON Power app	lications PC)				
Transmission protocol	-	TCP					
Data rate	•	100 Mbps					
Recommended cable category	CAT 6a or better						
DF–RT-link–high–speed RT interfa T communication between the CS		60 Input/Outputs Boxes (CIC	Ds))				
RT-link interface to connect CIOs is or	otional and not part of the	product delivery.					
Number of CIOs connected to CSU	3. Each CIO provides	4 analog input and 4 analog outp	out channels.				
Cable	2,2 mm jacketed plas	tic optic-fibre cable					
	Sample rate	1 MS/s per channel (there a	re 4 channels in one CIO)				
Upload (CIO to CSU)	Latency	≤ 45,5 µs (from the analog output)	g input of CIO to the CSU				
	Sample rate	256 kS/s per channel (there are 4 channels in					
Download (CSU to CIO)	Latency	Latency $\leq 5 \ \mu s$ (from the CSU output to the analog output of the CIO)					
w-voltage analog interface betwee	en CIOs and external H	IL platforms					
Analog input signals	Drives amplifier outpu	it voltages or currents.					
Analog output signals	Analog low-voltage measurements from t	outputs that transmit high-po he CDAs.	wer voltage and current				
Input/output voltage range	-10 V to 10 V						
Input impedance	50 kΩ						
Sampling rate	250 kHz						
ADC resolution	16 bit						
w-voltage digital interface (digital	interface between the	CIOs and external HIL platfo	orms)				
Digital input signals	Can be transmitted from CIO over POF–RT-link to the CCD. CCD sends the digital values over POF– or SFP–RT-link to external HIL or EGSTON RT Processor for further processing.						
Digital output signals		External HIL or EGSTON RT Processor can send digital values via SFP to the CSU control to drive the digital output signal of the CIOs.					
Logic levels	Input voltage levels:	$2 \text{ V} \leq \text{V}_{\text{IN}_{\text{HIGH}}} \leq 3,6 \text{ V}$	-0,3 V≤ V _{IN_LOW} ≤ 0,8 V				
(3,3 V LVCMOS)	Output voltage levels:	$3,1 V \le V_{OUT_HIGH}$	$V_{OUT_LOW} \le 0,2 V$				
Maximum currents	Input current:	IIN_MIN = -5 µA	IIN_MAX = 5 µA				
(3,3 V LVCMOS)	Output current:	I _{OUT_MIN} = -100 μA	I _{OUT_MAX} = 100 μA				



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COOLING REQUIREMENTS

Table 4. Cooling requirements

Liquid cooling (CDAs)	
Cooling media	Water, ethylene glycol, propylene glycol, glycol–water solutions
Minimum required cooling power	6,0 kW (for all 6 CDAs operating at full power)
Coolant pressure range	2,5–3 bar
Coolant flow rate for 6 CDAs	21I/min using water with an inlet temperature of 20°C
To avoid condensation, temperature of the	cooling liquid must be kept higher than the ambient temperature.
Forced-air cooling (cabinets)	
Maximum heat dissipation per	10,5 kW _{th}
CSU200-1GAMP6-HV at full power	

TECHNICAL DATA: MECHANICAL PROPERTIES

The CSU200-1GAMP6-HV system consists of four fixed free-standing cabinets. The dimensions and weight of each cabinet are listed in Table 5.

			-					
Mechanical data (cabinet dimensions)								
	w	idth	De	pth	He	eight	Weight	
	mm	ft	mm	ft	mm	ft	kg	Ib
Cabinet 1 transformer	1200	3,94	800	2,63	2450	8,03	1200	2645,5
Cabinet 2 AFE	1200	3,94	800	2,63	2390	7,84	700	1543,2
Cabinet 3 GAMP6	1200	3,94	800	2,63	2110	6,92	600	1322,7
Cabinet 4 output	600	1,97	800	2,63	2110	6,92	300	661,3
Total	4200	13,78	800	2,63	2450	8,03	2800	6172,7

Table 5. Dimensions and weight of CSU200-1GAMP6-HV cabinets

TESTING CAPABILITIES ACCORDING TO STANDARDS

Power grid:

- IEEE Std. 1547.1; usable as simulated area electric power systems source
- IEC 61000-3-12; meets requirements for power sources



MULTIPLE CSU200-1GAMP6-HV UNITS

Two to six CSU200-1GAMP6-HV units can be combined to form a COMPISO system with a total output power of up to 1.2 MW, without compromizing the flexibility of 6 galvanically isolated, centrally controlled 200 kW output channels.

The CSU200 units can be connected in series, in parallel, or in a combination of both, forming a COMPISO system with higher voltage, current, or both on the output. Such a system is controlled by a single Multi-GAMP Controller (MGC). MGC controls the voltage and current output of each CSU, making sure that all CSUs output the correct values for each operation mode. MGC also makes sure that voltage is shared equally between CSUs connected in series, and current is shared equally between CSUs connected in parallel.

The available voltage, current, and power range in each operation mode for multiple CSU200-1GAMP6-HV units connected in parallel are listed in Table 6, in series in Table 7, and in series & parallel in Table 8. All electrical values in Table 6, Table 7, and Table 8 are valid for an ambient temperature of 25°C.



CSU 200 UNITS CONNECTED IN PARALLEL

Table 6. Available voltage, current and power range in each operation mode for CSU200-1GAMP6-HV Units connected in parallel

Number of parallel CSUs	6	2	3	4	5	6
Minimum LL voltage	V_{LLmin}	0 V _{RMS}	0 V _{rms}	0 V _{RMS}	0 V _{RMS}	$0 V_{\text{RMS}}$
Maximum LL voltage	V _{LL max}	$485V_{\text{RMS}}$	$485 V_{RMS}$	$485 V_{\text{RMS}}$	$485 V_{\text{RMS}}$	$485 V_{RMS}$
Minimum current	I _{L min}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}
Maximum current	I _{L max}	480A _{RMS}	720 A _{RMS}	960 Arms	1200 A _{RMS}	1440 A _{RMS}
Maximum active power	P _{max}	400 kW	600 kW	800 kW	1000 kW	1200 kW
Maximum apparent power	S _{max}	400 kVA	600 kVA	800 kVA	1000 kVA	1200 kVA
Operation mode: Three-ph	ase (withou	ut N and with 3	B rd harmonic inj	ected)		
Number of parallel CSUs	5	2	3	4	5	6
Minimum LL voltage	V_{LLmin}	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$
Maximum LL voltage	V _{LL max}	$555 V_{\text{RMS}}$	$555 V_{\text{RMS}}$	$555 V_{\text{RMS}}$	$555 V_{\text{RMS}}$	$555 V_{\text{RMS}}$
Minimum current	I _{L min}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}
Maximum current	I _{L max}	480 A _{RMS}	720 A _{RMS}	960 A _{RMS}	1200 A _{RMS}	1440 A _{RMS}
Maximum active power	P _{max}	400 kW	600 kW	800 kW	1000 kW	1200 kW
Maximum apparent power	S _{max}	461 kVA	692 kVA	923 kVA	1153 kVA	1384 kVA
Operation mode: Three-ph	nase + N					
Number of parallel CSUs	6	2	3	4	5	6
Minimum LL voltage	V_{LLmin}	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$
Maximum LL voltage	$V_{\text{LL}\text{max}}$	$485 V_{\text{RMS}}$	$485V_{\text{RMS}}$	$485 V_{\text{RMS}}$	$485 V_{\text{RMS}}$	$485 V_{\text{RMS}}$
Maximum LN voltage	$V_{\text{LN}\text{max}}$	$280 \; V_{\text{RMS}}$	$280 \ V_{\text{RMS}}$	$280 \; V_{\text{RMS}}$	$280 \; V_{\text{RMS}}$	$280 \; V_{\text{RMS}}$
Maximum current	I _{L max}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}	0 A _{RMS}
Maximum current	I _{L max}	240 A _{RMS}	360 A _{RMS}	480 A _{RMS}	600 A _{RMS}	720 A _{RMS}
Maximum active power	P _{max}	200 kW	300 kW	400 kW	500 kW	600 kW
Maximum apparent power	S _{max}	200 kVA	300 kVA	400 kVA	500 kVA	600 kVA
Operation mode: Three-ph	nase + N (wi	ith 3 rd harmon	ic injected)			
Number of parallel CSUs	6	2	3	4	5	6
Minimum voltage	V_{LLmin}	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$
Maximum voltage	$V_{\text{LL}\text{max}}$	$555 V_{\text{RMS}}$	$555 V_{\text{RMS}}$	$555 V_{RMS}$	$555 V_{\text{RMS}}$	$555 V_{RMS}$
Maximum voltage	$V_{\text{LN}\text{max}}$	$320 V_{\text{RMS}}$	$320 V_{\text{RMS}}$	$320 V_{\text{RMS}}$	$320 V_{\text{RMS}}$	$320 V_{\text{RMS}}$
Maximum current	I _{L max}	240 A _{RMS}	$360 A_{RMS}$	480 A _{RMS}	600 A _{RMS}	720 A_{RMS}
Maximum active power	P _{max}	230 kW	345 kW	460 kW	575 kW	690 kW



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Onevetien meder Cingle :	-					
Dperation mode: Single Number of parallel CSUs	pnase	2	3	4	5	6
Minimum voltage	V _{min}	0 V _{RMS}	0 V _{RMS}	0 V _{RMS}	0 V _{RMS}	0 V _{RMS}
Maximum voltage	V _{min} V _{max}	565 V _{RMS}	565 V _{RMS}	565 V _{RMS}	565 V _{RMS}	565 V _{RMS}
Minimum current					0 A _{RMS}	
	I _{min}	0 A _{RMS}	0 A _{RMS} 1080 A _{RMS}	0 A _{RMS} 1440 A _{RMS}		0 A _{RMS}
Maximum current	I _{max}	720 A _{RMS}			1800 A _{RMS}	2160 A _{RMS}
Maximum active power	P _{max}	400 kW	600 kW	800 kW	1000 kW	1200 kW
Maximum apparent power	-	400 kVA	600 kVA	800 kVA	1000 kVA	1200 kVA
peration mode: DC bipo		2	2			
Number of parallel CSU			3	4	5	6
Minimum voltage	V _{min}	-800 V	-800 V	-800 V	-800 V	-800 V
Maximum voltage	V _{max}	800 V _{DC}	800 V _{DC}	800 V _{DC}	800 V _{DC}	800 V _{DC}
Minimum current	I _{min}	-840 A	-1260 A	-1680 A	-2100 A	-2520 A
Maximum current	I _{max}	840 A	1260 A	1680 A	2100 A	2520 A
Maximum power	P _{max}	400 kW	600 kW	800 kW	1000 kW	1200 kW
peration mode: DC unip						
Number of parallel CSU	Us	2	3	4	5	6
Minimum voltage	V _{min}	20 V	20 V	20 V	20 V	20 V
Maximum voltage	V _{max}	$820 V_{DC}$	$820 V_{DC}$	$820 V_{DC}$	820 V _{DC}	$820 V_{DC}$
Minimum current	I _{min}	-1680 A	-2520 A	-3360 A	-4200 A	-5040 A
Maximum current	I _{max}	1680 A	2520 A	3360 A	4200 A	5040 A
Maximum power	P _{max}	400 kW	600 kW	800 kW	1000 kW	1200 kW
)peration mode: Three-p	ohase + trans	sformer				
Number of parallel CS	Us	2	3	4	5	6
Minimum voltage	$V_{Lx-Lx\ min}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$	$0 V_{\text{RMS}}$
Maximum voltage	V _{Lx-Lx max} ¹	n · 565 V	n · 565 V	n · 565 V	n · 565 V	n · 565 V
Minimum current	I_{Lxmin}	0 A	0 A	0 A	0 A	0 A
Maximum current	I _{Lx max}	(2/n) ·120 A	(3/n) ·120 A	(4/n) ·120 A	(5/n) ∙120 A	(6/n) ∙120 A
Maximum active power	P _{max}	400 kW	600 kW	800 kW	1000 kW	1200 kW
Maximum power	S _{max}	400 kVA	600 kVA	800 kVA	1000 kVA	1200 kVA

Table 6. (continued)

Note:

n = Primary to secondary ratio



CSU 200 UNITS CONNECTED IN SERIES

Table 7. Available voltage, current and power range in each operation mode for CSU200-1GAMP6-HV Units connected in series

Operation mode: DC unipolar		
Number of CSUs in series		2 in series
Minimum voltage	V _{min}	40 V
Maximum voltage	V _{max}	1500 V
Maximum current	I _{max}	840 A
Maximum power	P _{max}	400 kW
Operation mode: DC bipolar		
Number of CSUs in series		2 in series
Minimum voltage	V _{min}	-1500 V _{DC}
Maximum voltage	V _{max}	1500 V _{DC}
Maximum current	I _{max}	420 A _{DC}
Maximum active power	P _{max}	400 kW
Note: With two output channels (Bipolar Output) Number of CSUs in series	with midpoint grounded	4 in series
Minimum voltage	V _{min}	0 V
Maximum voltage	V _{max}	±1500 V (per output channel)
Maximum current	I _{max}	420 A
Maximum power	P _{max}	400 kW (per output channel)
Operation mode: Single phase		
Number of CSUs in series		2 in series
Minimum voltage	V _{min}	0 V _{RMS}
Maximum voltage (per channel)	V _{max}	1000 V _{RMS}
Maximum current	I _{max}	360 A _{RMS}
Maximum power	P _{max}	360 kW
Maximum apparent power	S _{max}	360 kVA



CSU 200 UNITS CONNECTED IN SERIES & PARALLEL

Table 8. Available voltage, current and power range in each operation mode for CSU200-1GAMP6-HV Units connected in series and parallel

CSU Connection overiew

Number of CSUs in series & parallel		4 system in series & parallel	6 system in series & parallel
Operation mode: DC unipola	r		
Minimum voltage	V _{min}	40 V	40 V
Maximum voltage	V _{max}	1500 V	1500 V
Maximum current	I _{max}	1680 A	2520 A
Maximum power	P _{max}	800 kW	1.2 MW
Operation mode: DC bipolar			
Minimum voltage	V _{min}	-1500 V _{DC}	-1500 VDC
Maximum voltage	V _{max}	1500 V _{DC}	1500 VDC
Maximum current	I _{max}	840 A _{DC}	1260 ADC
Maximum power	P _{max}	800 kW	1.2 MW
Operation mode: Single phas	se		
Minimum voltage	V _{min}	0 VRMS	0 VRMS
Maximum voltage	V _{max}	1000 VRMS	1000 VRMS
Maximum current	I _{max}	720 ARMS	1080 ARMS
Maximum active power	P _{max}	720 kW	1.08 MW
Maximum apparent power	S _{max}	720 kVA	1.08 MVA

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